## MSKSEMI















**ESD** 

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# Broduct data sheet





#### **FEATURES**

- Small Package
- Low Reverse Current
- Fast Switching Speed
- Surface Mount Package Ideally Suited for Automatic Insertion

**MARKING: T5** 

**SOD-323** 



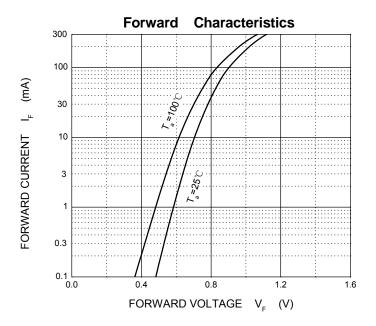
## Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25℃

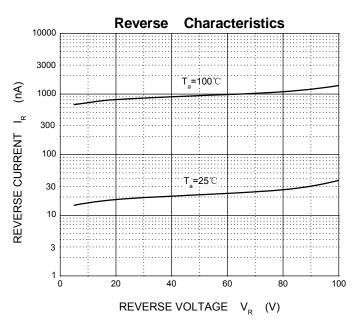
Parameter	Symbol	Limit	Unit
Non-Repetitive Peak Reverse Voltage	$V_{RM}$	100	V
Peak Repetitive Peak Reverse Voltage	$V_{RRM}$		
Working Peak Reverse Voltage	$V_{RWM}$	75	V
DC Blocking Voltage	$V_{R}$		
RMS Reverse Voltage	$V_{R(RMS)}$	53	V
Forward Continuous Current	I <sub>FM</sub>	500	mA
Average Rectified Output Current	Io	250	mA
Non-Repetitive Peak Forward Surge Current @t=8.3ms	I <sub>FSM</sub>	2.0	Α
Power Dissipation	Pd	200	mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	625	°C/W
Operation Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~+150	℃

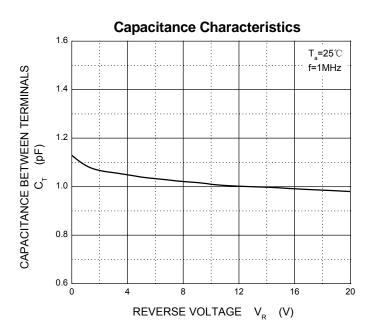
#### Electrical Ratings @Ta=25℃

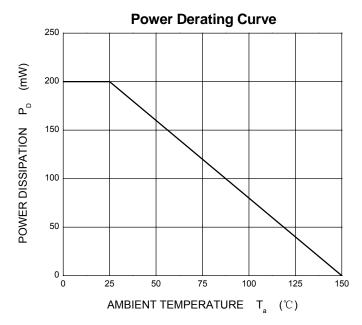
Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Reverse Breakdown Voltage	V <sub>(BR)R</sub>	75			V	Ir=10µA
Forward Voltage	V <sub>F1</sub>	0.62		0.72	V	I <sub>F</sub> =5mA
	V <sub>F2</sub>			0.855	V	I <sub>F</sub> =10mA
	$V_{F3}$			1.0	V	I <sub>F</sub> =100mA
	V <sub>F4</sub>			1.25	V	I <sub>F</sub> =150mA
Reverse Current	I <sub>R1</sub>			2.5	μA	V <sub>R</sub> =75V
	I <sub>R2</sub>			25	nA	V <sub>R</sub> =20V
Capacitance Between Terminals	Ст			4	pF	V <sub>R</sub> =0V,f=1MHz
Reverse Recovery Time	t <sub>rr</sub>			4	ns	I <sub>F</sub> =I <sub>R</sub> =10mA
Neverse Necovery Time						Irr=0.1 $XI_R$ , $R_L$ =100 $\Omega$





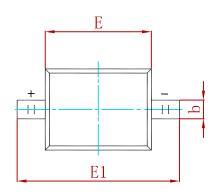


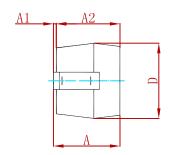


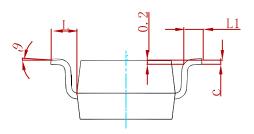




## PACKAGE MECHANICAL DATA

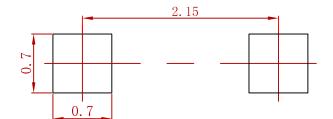






Cumbal	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α		1.000		0.039	
A1	0.000	0.100	0.000	0.004	
A2	0.800	0.900	0.031	0.035	
b	0.250	0.350	0.010	0.014	
С	0.080	0.150	0.003	0.006	
D	1.200	1.400	0.047	0.055	
E	1.600	1.800	0.063	0.071	
E1	2.550	2.750	0.100	0.108	
L	0.475	REF.	0.019	REF.	
L1	0.250	0.400	0.010	0.016	
θ	0°	8°	0°	8°	

## **Suggested Pad Layout**



### Note:

- 1. Controlling dimension: in millimeters.
- 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.

## **REEL SPECIFICATION**

P/N	PKG	QTY
1N4448WS	SOD-323	3000



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